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April 2004 Revised June 2004

FXL4T245

Low Voltage Dual Supply 4-Bit Signal Translator with Configurable Voltage Supplies and Signal Levels and 3-STATE Outputs

General Description

The FXL4T245 is a configurable dual-voltage-supply translator designed for bi-directional voltage translation of signals between two voltage levels. The device allows translation between voltages as high as 3.6V to as low as 1.1V. The A Port tracks the $V_{\rm CCA}$ level, and the B Port tracks the $V_{\rm CCB}$ level. Both ports are designed to accept supply voltage levels from 1.1V to 3.6V. This allows for bi-directional voltage translation over a variety of voltage levels: 1.2V, 1.5V, 1.8V, 2.5V, and 3.3V.

The device remains in 3-STATE until both $V_{CC}s$ reach active levels allowing either V_{CC} to be powered-up first. The device also contains power down control circuits that place the device in 3-STATE if either V_{CC} is removed.

The Transmit/Receive (T/\overline{R}) input determines the direction of data flow through the device. The \overline{OE} input, when HIGH, disables both the A and B Ports by placing them in 3-STATE condition. The FXL4T245 is designed so that the control pins $(T/\overline{R}$ and $\overline{OE})$ are supplied by V_{CGA} .

Features

- Bi-directional interface between any 2 levels from 1.1V to 3.6V
- \blacksquare Fully configurable, inputs track V_CC level
- Non-preferential power-up sequencing; either V_{CC} may be powered-up first
- No power-up sequencing required
- Outputs remain in 3-STATE until active V_{CC} level is reached
- \blacksquare Outputs switch to 3-STATE if either V_{CC} is at GND
- Power-off protection
- Control inputs (T/R, OE) levels are referenced to V_{CCA} voltage
- Packaged in 14-terminal DQFN (2.5mm x 3.0mm) package
- ESD protection exceeds:
 - 4kV HBM ESD (per JESD22-A114 & Mil Std 883e 3015.7)
 - 8kV HBM I/O to GND ESD (per JESD22-A114 & Mil Std 883e 3015.7)
 - 1kV CDM ESD (per ESD STM 5.3)
 - 200V MM ESD (per JESD22-A115 & ESD STM5.2)

Ordering Code:

Order Number	Package Number	Package Description
FXL4T245BQX	MLP014A	14-Terminal Depopulated Quad Very-Thin Flat Pack No Leads (DQFN), JEDEC MO-241, 2.5 x 3.0mm

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DS500891

Terminal Descriptions

Terminal Names	Description						
ŌE	Output Enable Input						
T/R	Transmit/Receive Input						
A _n	Side A Inputs or 3-STATE Outputs						
B _n	Side B Inputs or 3-STATE Outputs						
V_{CCA}	Side A Power Supply						
V _{CCB}	Side B Power Supply						
GND	Ground						

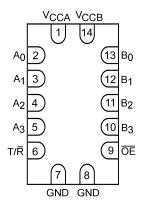
Truth Table

ĺ	Inp	uts	Outputs
	ŌE	T/R	
ĺ	L	L	Bus B Data to Bus A
	L	Н	Bus A Data to Bus B

H = HIGH Voltage Level

Connection Diagram

Terminal Assignments for DQFN



(Top View)

Terminal Assignment

Terminal Number	Terminal Name
1	V _{CCA}
2	A ₀
3	A ₁
4	A ₂
5	A ₃
6	T/R
7	GND
8	GND
9	ŌĒ
10	В ₃
11	B ₂
12	B ₁
13	B ₀
14	V _{CCB}

Power-Up/Power-Down Sequencing

FXL translators offer an advantage in that either V_{CC} may be powered up first. This benefit derives from the chip design. When either V_{CC} is at 0 volts, outputs are in a HIGH-Impedance state. The control inputs $(T/\overline{R} \text{ and } \overline{OE})$ are designed to track the V_{CCA} supply. A pull-up resistor tying \overline{OE} to V_{CCA} should be used to ensure that bus contention, excessive currents, or oscillations do not occur during power-up/power-down. The size of the pull-up resistor is based upon the current-sinking capability of the \overline{OE} driver.

The recommended power-up sequence is the following:

- 1. Apply power to either $V_{\mbox{\footnotesize CC}}$.
- Apply power to the T/R input (Logic HIGH for A-to-B operation; Logic LOW for B-to-A operation) and to the respective data inputs (A Port or B Port). This may occur at the same time as Step 1.
- 3. Apply power to other V_{CC} .
- 4. Drive the $\overline{\text{OE}}$ input LOW to enable the device.

The recommended power-down sequence is the following:

- 1. Drive OE input HIGH to disable the device.
- 2. Remove power from either V_{CC} .
- 3. Remove power from other V_{CC} .

L = LOW Voltage Level

X = Don't Care

Absolute Maximum Ratings(Note 1)

Recommended Operating Conditions (Note 3)

Supply Voltage		Conditions (Note 3)	
V_{CCA}	-0.5V to $+4.6V$	Power Supply Operating (V_{CCA} or V_{CCB})	1.1V to 3.6
V _{CCB}	-0.5V to $+4.6V$	Input Voltage	
DC Input Voltage (V _I)		Port A	0.0V to 3.6

0.0V to 3.6V I/O Port A -0.5V to +4.6VPort B 0.0V to 3.6V I/O Port B -0.5V to +4.6V Control Inputs $(T/\overline{R}, \overline{OE})$ 0.0V to $V_{\mbox{\footnotesize CCA}}$ Control Inputs (T/R, OE) -0.5V to +4.6V Output Current in I_{OH}/I_{OL}

Output Voltage (V_O) (Note 2) V_{CC}

Outputs 3-STATE -0.5V to +4.6V3.0V to 3.6V ±24 mA Outputs Active (A_n) -0.5V to $V_{CCA} + 0.5V$ 2.3V to 2.7V ±18 mA Outputs Active (B_n) -0.5V to $V_{CCB} + 0.5V$ 1.65V to 1.95V ±6 mA DC Input Diode Current (I_{IK}) $V_I < 0V$ -50 mA ±2 mA 1.4V to 1.65V DC Output Diode Current (I_{OK}) 1.1V to 1.4V ±0.5 mA $V_{O} < 0V$ -40°C to +85°C -50 mA Free Air Operating Temperature (T_A)

 $V_{O} > V_{CC}$ +50 mA Minimum Input Edge Rate $(\Delta V/\Delta t)$

 $V_{CCA/B} = 1.1V$ to 3.6VDC Output Source/Sink Current 10 ns/V

-50 mA / +50 mA (I_{OH}/I_{OL}) DC V_{CC} or Ground Current per

Note 1: The "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Supply Pin (I_{CC}) ±100 mA Characteristics tables are not guaranteed at the absolute maximum ratings. Storage Temperature Range (T_{STG}) -65°C to +150°C

The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 2: I_O Absolute Maximum Rating must be observed.

Note 3: All unused inputs must be held at $\rm V_{\rm CCI}$ or GND.

DC Electrical Characteristics

Symbol	Parameter	Conditions	V _{CCI}	V _{cco}	Min	Max	Units
Cymbol	T drameter	Contactions	(V)	(V)		WILL	Omico
V _{IH}	High Level Input Voltage	Data Inputs A _n , B _n	2.7 - 3.6		2.0		
(Note 4)			2.3 - 2.7		1.6		
			1.65 - 2.3	1.1 - 3.6	0.65 x V _{CCI}		
			1.4 - 1.65		0.65 x V _{CCI}		
			1.1 - 1.4		0.9 x V _{CCI}		V
		Control Pins/OE, T/R	2.7 - 3.6		2.0		V
		(Referenced to V _{CCA})	2.3 - 2.7		1.6		
			1.65 - 2.3	1.1 - 3.6	0.65 x V _{CCA}		
			1.4 - 1.65		0.65 x V _{CCA}		
			1.1 - 1.4		0.9 x V _{CCA}		
V _{IL}	Low Level Input Voltage	Data Inputs A _n , B _n	2.7 - 3.6			8.0	
(Note 4)			2.3 - 2.7			0.7	
			1.65 - 2.3	1.1 - 3.6		0.35 x V _{CCI}	
			1.4 - 1.65			0.35 x V _{CCI}	
			1.1 - 1.4			0.1 x V _{CCI}	V
		Control Pins/OE, T/R	2.7 - 3.6			8.0	V
		(Referenced to V _{CCA})	2.3 - 2.7			0.7	
			1.65 - 2.3	1.1 - 3.6		0.35 x V _{CCA}	
			1.4 - 1.65			0.35 x V _{CCA}	
			1.1 - 1.4			0.1 x V _{CCA}	

DC Electrical Characteristics (Continued) V_{CCA} V_{CCB} Conditions Symbol Parameter Min Max Units (V) (V) $I_{OH} = -100 \mu A$ High Level Output Voltage 1.1 - 3.61.1 - 3.6V_{CC0} - 0.2 $I_{OH} = -12 \text{ mA}$ (Note 5) 2.7 2.7 2.2 $I_{OH} = -18 \text{ mA}$ 3.0 3.0 2.4 $I_{OH} = -24 \text{ mA}$ 3.0 3.0 2.2 $I_{OH} = -6 \text{ mA}$ 2.3 2.3 2.0 ٧ $I_{OH} = -12 \text{ mA}$ 2.3 2.3 1.8 $I_{OH} = -18 \text{ mA}$ 2.3 2.3 1.7 $I_{OH} = -6 \text{ mA}$ 1.65 1.25 $I_{OH} = -2 \text{ mA}$ 1.4 1.4 $I_{OH} = -0.5 \text{ mA}$ 1.1 1.1 $0.75 \times V_{CC0}$ $I_{OL} = 100 \mu A$ Low Level Output Voltage 1.1 - 3.6 1.1- 3.6 V_{OL} 0.2 (Note 5) $I_{OL} = 12 \text{ mA}$ 2.7 2.7 0.4 $I_{OL} = 18 \text{ mA}$ 3.0 3.0 0.4 0.55 $I_{OL} = 24 \text{ mA}$ 3.0 3.0 I_{OL} =12 mA 2.3 2.3 0.4 $I_{OL} = 18 \text{ mA}$ 2.3 2.3 0.6 $I_{OL} = 6 \text{ mA}$ 1.65 1.65 $I_{OL} = 2 \text{ mA}$ 1.4 0.35 0.3 x V_{CC0} $I_{OL} = 0.5 \text{ mA}$ 1.1 1.1 $V_I = V_{CCA}$ or GND 1.1 - 3.6 Input Leakage Current. Control Pins 3.6 +1.0 цΑ A_{n} , V_{I} or $V_{O} = 0$ V to 3.6V Power Off Leakage Current ±10.0 3.6 I_{OFF} 0 μΑ B_n , V_I or $V_O = 0V$ to 3.6V 3.6 0 ±10.0 $\overline{\text{OE}} = V_{\text{IH}}$ 3-STATE Output Leakage A_n, B_n 3.6 3.6 ±10.0 OE = Don't Care (Note 6) B_n, 3.6 +10.0 $0 \le V_O \le 3.6 V$ μΑ OE = Don't Care 0 +10.0 $V_I = V_{IH}$ or V_{IL} 3.6 I_{CCA/B} (Note 7) Quiescent Supply Current $V_I = V_{CCI}$ or GND; $I_O = 0$ 1.1 - 3.6 1.1 - 3.6 20.0 μА I_{CCZ} (Note 7) Quiescent Supply Current $V_I = V_{CCI}$ or GND; $I_O = 0$ 1.1 - 3.6 1.1 - 3.6 20.0 μΑ Quiescent Supply Current $V_I = V_{CCA}$ or GND; $I_O = 0$ 0 1.1 - 3.6 -10.0 μΑ I_{CCA} $V_I = V_{CCA}$ or GND; $I_O = 0$ 1.1 - 3.6 0 10.0 μΑ Quiescent Supply Current $V_I = V_{CCB}$ or GND; $I_O = 0$ I_{CCB} 1.1 - 3.6 0 -10.0 μΑ $V_I = V_{CCB}$ or GND; $I_O = 0$ 1.1 - 3.6 10.0 0 μΑ $\Delta I_{CCA/B}$ Increase in I_{CC} per Input; μΑ Other Inputs at V_{CC} or GND

Note 4: V_{CCI} = the V_{CC} associated with the data input under test.

Note 5: $V_{CCO} = \text{the } V_{CC}$ associated with the output under test.

Note 6: Don't Care = Any valid logic level.

Note 7: Reflects current per supply, V_{CCA} or V_{CCB} .

AC Electrical Characteristics $v_{\text{CCA}} = 3.0 \text{V to } 3.6 \text{V}$

	Parameter	$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$										
Symbol		V _{CCB} = 3.0V to 3.6V		V _{CCB} = 2.3V to 2.7V		V _{CCB} = 1.65V to 1.95V		V _{CCB} = 1.4V to 1.6V		V _{CCB} = 1.1V to 1.3V		Units
		Min	Max	Min	Max	Min	Max	Min	Max	Min	Max	1
t _{PLH} , t _{PHL}	Propagation Delay A to B	0.2	3.5	0.3	3.9	0.5	5.4	0.6	6.8	1.4	22.0	ns
	Propagation Delay B to A	0.2	3.5	0.2	3.8	0.3	4.0	0.5	4.3	0.8	13.0	115
t _{PZH} , t _{PZL}	Output Enable OE to B	0.5	4.0	0.7	4.4	1.0	5.9	1.0	6.4	1.5	17.0	ns
	Output Enable OE to A	0.5	4.0	0.5	4.0	0.5	4.0	0.5	4.0	0.5	4.0	115
t _{PHZ} , t _{PLZ}	Output Disable OE to B	0.2	3.8	0.2	4.0	0.7	4.8	1.5	6.2	2.0	17.0	ns
	Output Disable OE to A	0.2	3.7	0.2	3.7	0.2	3.7	0.2	3.7	0.2	3.7	115

AC Electrical Characteristics $v_{\text{CCA}} = 2.3 \text{V to } 2.7 \text{V}$

		$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$										
Symbol	Parameter	V _{CCB} = 3.0V to 3.6V		V _{CCB} = 2.3V to 2.7V		V _{CCB} = 1.65V to 1.95V		V _{CCB} = 1.4V to 1.6V		V _{CCB} = 1.1V to 1.3V		Units
		Min	Max	Min	Max	Min	Max	Min	Max	Min	Max	Ī
t _{PLH} , t _{PHL}	Propagation Delay A to B	0.2	3.8	0.4	4.2	0.5	5.6	0.8	6.9	1.4	22.0	ns
	Propagation Delay B to A	0.3	3.9	0.4	4.2	0.5	4.5	0.5	4.8	1.0	7.0	113
t _{PZH} , t _{PZL}	Output Enable OE to B	0.6	4.2	0.8	4.6	1.0	6.0	1.0	6.8	1.5	17.0	ns
	Output Enable OE to A	0.6	4.5	0.6	4.5	0.6	4.5	0.6	4.5	0.6	4.5	115
t _{PHZ} , t _{PLZ}	Output Disable OE to B	0.2	4.1	0.2	4.3	0.7	4.8	1.5	6.7	2.0	17.0	ns
	Output Disable OE to A	0.2	4.0	0.2	4.0	0.2	4.0	0.2	4.0	0.2	4.0	115

AC Electrical Characteristics $v_{\text{CCA}} = 1.65 v$ to 1.95 v

		$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$										
Symbol	Parameter		_{CB} =		_{CB} = o 2.7V		_{CB} = o 1.95V		_{CB} = o 1.6V		_{CB} =	Units
		Min	Max	Min	Max	Min	Max	Min	Max	Min	Max	1
t _{PLH} , t _{PHL}	Propagation Delay A to B	0.3	4.0	0.5	4.5	0.8	5.7	0.9	7.1	1.5	22.0	ns
	Propagation Delay B to A	0.5	5.4	0.5	5.6	0.8	5.7	1.0	6.0	1.2	8.0	113
t _{PZH} , t _{PZL}	Output Enable OE to B	0.6	5.2	0.8	5.4	1.2	6.9	1.2	7.2	1.5	18.0	no
	Output Enable OE to A	1.0	6.7	1.0	6.7	1.0	6.7	1.0	6.7	1.0	6.7	ns
t _{PHZ} , t _{PLZ}	Output Disable OE to B	0.2	5.1	0.2	5.2	0.8	5.2	1.5	7.0	2.0	17.0	ns
	Output Disable OE to A	0.5	5.0	0.5	5.0	0.5	5.0	0.5	5.0	0.5	5.0] 115

AC Electrical Characteristics $V_{\text{CCA}} = 1.4 \text{V to } 1.6 \text{V}$

		$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$										
Symbol	Parameter	V _{CCB} = 3.0V to 3.6V			V _{CCB} = 2.3V to 2.7V		V _{CCB} = 1.65V to 1.95V		_{CB} = o 1.6V	V _{CCB} = 1.1V to 1.3V		Units
		Min	Max	Min	Max	Min	Max	Min	Max	Min	Max	Ì
t _{PLH} , t _{PHL}	Propagation Delay A to B	0.5	4.3	0.5	4.8	1.0	6.0	1.0	7.3	1.5	22.0	ns
	Propagation Delay B to A	0.6	6.8	0.8	6.9	0.9	7.1	1.0	7.3	1.3	9.5	113
t _{PZH} , t _{PZL}	Output Enable OE to B	1.1	7.5	1.1	7.6	1.3	7.7	1.4	7.9	2.0	20.0	ns
	Output Enable OE to A	1.0	7.5	1.0	7.5	1.0	7.5	1.0	7.5	1.0	7.5	115
t _{PHZ} , t _{PLZ}	Output Disable OE to B	0.4	6.1	0.4	6.2	0.9	6.2	1.5	7.5	2.0	18.0	ns
	Output Disable OE to A	1.0	6.0	1.0	6.0	1.0	6.0	1.0	6.0	1.0	6.0	115

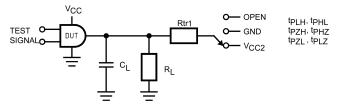
AC Electrical Characteristics $v_{\text{CCA}} = 1.1 \text{V to } 1.3 \text{V}$

		$T_A = -40^{\circ}C$ to $+85^{\circ}C$										
Symbol	Parameter	V _{CCB} = 3.0V to 3.6V		V _{CCB} = 2.3V to 2.7V		V _{CCB} = 1.65V to 1.95V		V _{CCB} = 1.4V to 1.6V		V _{CCB} = 1.1V to 1.3V		Units
		Min	Max	Min	Max	Min	Max	Min	Max	Min	Max	
t _{PLH} , t _{PHL}	Propagation Delay A to B	0.8	13.0	1.0	7.0	1.2	8.0	1.3	9.5	2.0	24.0	ns
	Propagation Delay B to A	1.4	22.0	1.4	22.0	1.5	22.0	1.5	22.0	2.0	24.0	113
t _{PZH} , t _{PZL}	Output Enable OE to B	1.0	12.0	1.0	9.0	2.0	10.0	2.0	11.0	2.0	24.0	no
	Output Enable OE to A	2.0	22.0	2.0	22.0	2.0	22.0	2.0	22.0	2.0	22.0	ns
t _{PHZ} , t _{PLZ}	Output Disable OE to B	1.0	15.0	0.7	7.0	1.0	8.0	2.0	10.0	2.0	20.0	ns
	Output Disable OE to A	2.0	15.0	2.0	12.0	2.0	12.0	2.0	12.0	2.0	12.0	115

Capacitance

Symbol	Parameter	Conditions	$T_A = +25^{\circ}C$	Units	
Cymbol	i didilictei	Conditions	Typical	Oillio	
C _{IN}	Input Capacitance Control Pins (OE, T/R)	$V_{CCA} = V_{CCB} = 3.3V$, $V_I = 0V$ or $V_{CCA/B}$	4.0	pF	
C _{I/O}	Input/Output Capacitance A _n , B _n Ports	$V_{CCA} = V_{CCB} = 3.3V$, $V_I = 0V$ or $V_{CCA/B}$	5.0	pF	
C _{PD}	Power Dissipation Capacitance	$V_{CCA} = V_{CCB} = 3.3V$, $V_I = 0V$ or V_{CC} , $F = 10$ MHz	20.0	pF	

AC Loading and Waveforms

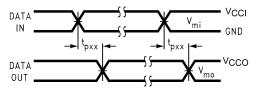


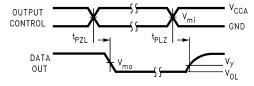
TEST	SWITCH				
t _{PLH} , t _{PHL}	OPEN				
t _{PLZ} , t _{PZL}	V_{CCO} x 2 at V_{CCO} = 3.3 ± 0.3V, 2.5V ± 0.2V, 1.8V ± 0.15V, 1.5V ± 0.1V, 1.2V ± 0.1V				
t _{PHZ} , t _{PZH}	GND				

FIGURE 1. AC Test Circuit

AC Load Table

V _{cco}	CCO CL RL		Rtr1	
1.2V ± 0.1V	15 pF	2 kΩ	2 kΩ	
1.5V ± 0.1V	15 pF	2 kΩ	2 kΩ	
1.8V ± 0.15V	15 pF	2 kΩ	2 kΩ	
2.5V ± 0.2V	15 pF	2 kΩ	2 kΩ	
3.3V ± 0.3V	15 pF	2 kΩ	2 kΩ	





Note: Input $t_{\mbox{\scriptsize R}}=t_{\mbox{\scriptsize F}}=2.0$ ns, 10% to 90%

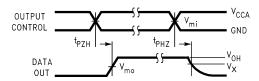
Input $t_{R}=t_{F}=2.5 ns,\,10\%$ to 90%, @ $V_{I}=3.0 V$ to 3.6V only

FIGURE 2. Waveform for Inverting and Non-Inverting Functions

Note: Input $t_R = t_F = 2.0 \text{ ns}$, 10% to 90%

Input $t_R = t_F = 2.5 \text{ns}$, 10% to 90%, @ $V_I = 3.0 \text{V}$ to 3.6V only

FIGURE 3. 3-STATE Output Low Enable and Disable Times for Low Voltage Logic



Note: Input $t_R = t_F = 2.0 \text{ ns}$, 10% to 90%

Input $t_R = t_F = 2.5 \text{ns}$, 10% to 90%, @ $V_I = 3.0 \text{V}$ to 3.6V only

FIGURE 4. 3-STATE Output High Enable and Disable Times for Low Voltage Logic

Symbol	V _{CC}				
	$3.3V \pm 0.3V$	2.5V ± 0.2V	1.8V ± 0.15V	1.5V ± 0.1V	1.2V ± 0.1V
V _{mi}	V _{CCI} /2	V _{CCI} /2	V _{CCI} /2	V _{CCI} /2	V _{CCI} /2
V _{mo}	V _{CCO} /2	V _{CCO} /2	V _{CCO} /2	V _{CCO} /2	V _{CCO} /2
V _X	V _{OH} – 0.3V	V _{OH} – 0.15V	V _{OH} – 0.15V	V _{OH} – 0.1V	V _{OH} – 0.1V
V _Y	V _{OL} + 0.3V	V _{OL} + 0.15V	V _{OL} + 0.15V	V _{OL} + 01V	V _{OL} + 01V

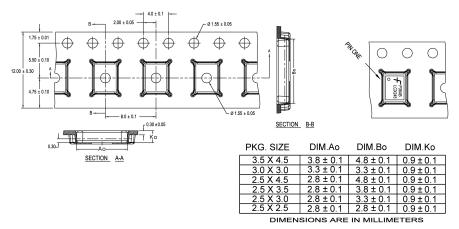
Note: For V_{mi} : $V_{CCI} = V_{CCA}$ for Control Pins T/\overline{R} and \overline{OE} , or $V_{CCA}/2$

Tape and Reel Specification

Tape Format for DQFN

Package	Tape	Number	Cavity	Cover Tape
Designator	Section	Cavities	Status	Status
	Leader (Start End)	125 (typ)	Empty	Sealed
BQX	Carrier	3000	Filled	Sealed
	Trailer (Hub End)	75 (typ)	Empty	Sealed

TAPE DIMENSIONS inches (millimeters)

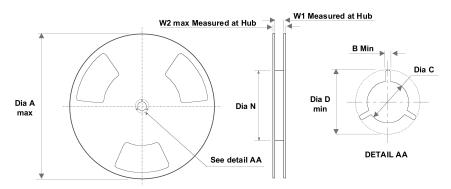


NOTES: unless otherwise specified

- 1. Cummulative pitch for feeding holes and cavities (chip pockets) not to exceed 0.008[0.20] over 10 pitch span.
- Smallest allowable bending radius.
 Thru hole inside cavity is centered within cavity.

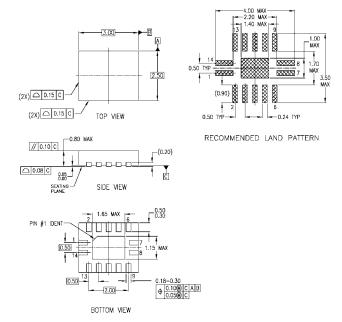
- 3. This hole instead early is centered within Early.
 4. Tolerance is ±0.002[0.05] for these dimensions on all 12mm tapes.
 5. Ao and Bo measured on a plane 0.120[0.30] above the bottom of the pocket.
 6. Ko measured from a plane on the inside bottom of the pocket to the top surface of the carrier.
 7. Pocket position relative to sprocket hole measured as true position of pocket. Not pocket hole.
- 8. Controlling dimension is millimeter. Diemension in inches rounded.

REEL DIMENSIONS inches (millimeters)



Tape Size	Α	В	С	D	N	W1	W2
12 mm	13.0	0.059	0.512	0.795	2.165	0.488	0.724
	(330.0)	(1.50)	(13.00)	(20.20)	(55.00)	(12.4)	(18.4)

Physical Dimensions inches (millimeters) unless otherwise noted



NOTES:

- A. CONFORMS TO JEDEC REGISTRATION MO-241, VARIATION AA
 B. DIMENSIONS ARE IN MILLIMETERS.
 C. DIMENSIONS AND TOLERANCES PER ASME Y14.5M, 1994

MLP014ArevA

14-Terminal Depopulated Quad Very-Thin Flat Pack No Leads (DQFN), JEDEC MO-241, 2.5 x 3.0mm Package Number MLP014A

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